## NSN 5961-01-047-9097

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-047-9097 **Inclosure Material:** Metal **Overall Length:** 1.090 inches **Overall Height:** 0.750 inches **Overall Width:** 0.850 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 225.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 0.40 amperes forward current, average absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** External surfaces silver **Precious Material:** Silver **Terminal Type And Quantity:** 6 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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